TOSHIBA 2SK709

TOSHIBA FIELD EFFECT TRANSISTOR SILICON N CHANNEL JUNCTION TYPE

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HIGH FREOUENCY AMPLIFIER APPLICATIONS AM HIGH FREQUENCY AMPLIFIER APPLICATIONS AUDIO FREQUENCY AMPLIFIER APPLICATIONS

High $|Y_{fs}| : |Y_{fs}| = 25 \text{ mS (Typ.)}$

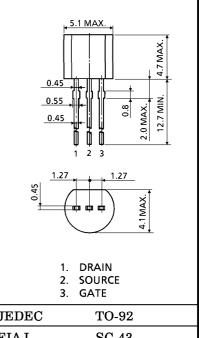
Low C_{iss} : $C_{iss} = 7.5 pF$ (Typ.)

Low Noise

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Gate-Drain Voltage	v_{GDS}	-20	V
Gate Current	$I_{\mathbf{G}}$	10	mA
Drain Power Dissipation	$P_{\mathbf{D}}$	300	mW
Junction Temperature	T_{j}	125	°C
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~125	°C

Unit in mm



JEDEC	TO-92	
EIAJ	SC-43	
TOSHIBA	2-5F1A	

Weight: 0.21 g

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gate Leakage Current	$I_{ m GSS}$	$V_{GS} = -15 \text{ V}, V_{DS} = 0$	_	_	-1.0	nA
Gate-Drain Breakdown Voltage	V _(BR) GDS	$V_{DS} = 0, I_{G} = -100 \mu A$	-20	_	_	V
Drain Current	I _{DSS} (Note)	$V_{DS} = 5 V$, $V_{GS} = 0$	6	_	32	mA
Gate-Source Cut-off Voltage	V _{GS} (OFF)	$V_{DS} = 5 \text{ V}, I_{D} = 1 \mu A$	_	_	-2.5	V
Forward Transfer Admittance	$ Y_{fs} $	$V_{DS} = 5 V$, $V_{GS} = 0$, $f = 1 \text{kHz}$	15	25	_	mS
Input Capacitance	C_{iss}	$V_{DS} = 5 \text{ V}, V_{GS} = 0,$ f = 1 MHz	_	7.5	10	pF
Reverse Transfer Capacitance	C_{rss}	$V_{\mathrm{DG}} = 5 \mathrm{V}, \mathrm{I_D} = 0,$ $\mathrm{f} = 1 \mathrm{MHz}$	_	2	3	pF
Noise Figure	NF	$egin{aligned} V_{ ext{DS}} = 5 & ext{V}, \ I_{ ext{D}} = 1 & ext{mA} \ R_{ ext{g}} = 1 & ext{k}\Omega, \ f = 1 & ext{kHz} \end{aligned}$	_	0.5	3	dB

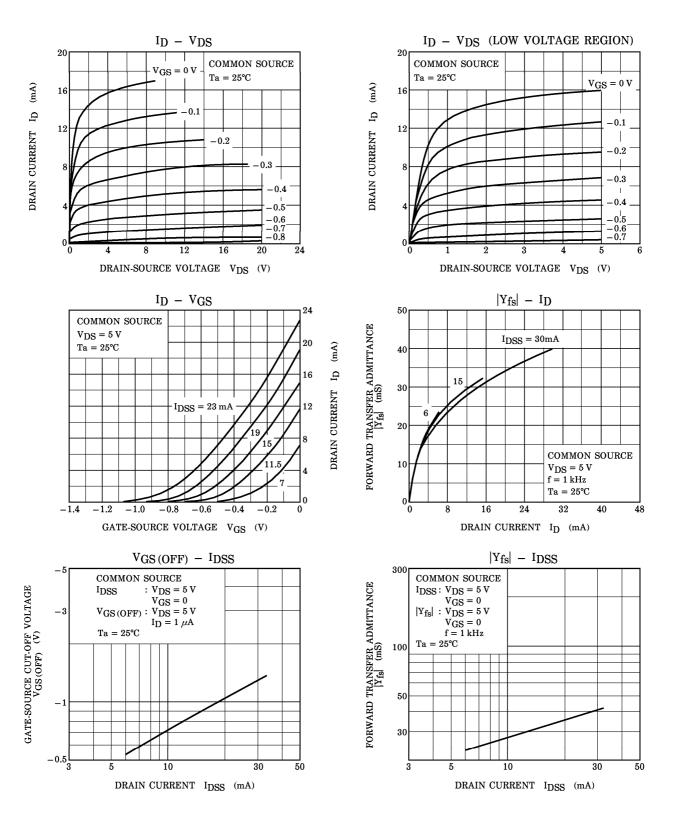
(Note): IDSS Classification $GR: 6\sim 12 \text{ mA}, BL: 10\sim 20 \text{ mA}, V: 16\sim 32 \text{ mA}$

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